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Supplementary Materials for

Optimization of oxygen evolution activity by tuning e_g^* band broadening in nickel oxyhydroxide

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Materials and Methods

Materials. Ni(NO)₃· $6H_2O$, Fe(NO₃)₃· $9H_2O$, Urea, Sulfur, Selenium, Sodium phosphate monobasic, Potassium sulfate, Sodium selenite, and 5wt.% Nafion solution were purchased from the Sigma-Aldrich. These chemicals were reagent grade and used without further purification.

Synthesis of the X-Ni(OH)₂ (X=NiS₂, NiSe₂, Ni₅P₄)

- (1) Synthesis of Ni(OH)₂ on carbon cloth. The Ni(OH)₂ was grown on the carbon cloth via a facile hydrothermal method. Before that, the carbon cloth was pre-treated under 500 °C for 1h in the air condition and dealt with Ultra-Violet Ozone for 30 min to make it fully hydrophilic. Next, 2mmol Ni(NO)₃·6H₂O, 10mmol Urea were added into 35 mL DI water and stirred for 15 min to form uniform solution. One piece of carbon cloth with size of 2 cm × 3 cm was immersed into the solution. Then, they were transferred into a 50 mL Teflon-lined stainless-steel autoclave and kept at 120 °C for 10h. The obtained Ni(OH)₂ was then washed by DI water for three times to remove the solution and loosely adhered Ni(OH)₂ powder. Finally, the Ni(OH)₂ was dried under 70 °C in air for 4h.
- (2) Preparation of NiS₂, NiSe₂, Ni₅P₄. When preparing NiS₂, the 2 cm × 3 cm carbon cloth loaded Ni(OH)₂ sample was placed at the downstream position in the crucible, while 400 mg sulfur powder was placed at the upstream position. The sample was kept at 400 °C for 2h under N₂ atmosphere and then cool down to temperature. After that, the obtained NiS₂ was washed using DI water and dried at 70 °C for 1h. The synthesis procedures of NiSe₂ and Ni₅P₄ were the same as that of NiS₂, except that the anion source was selenium and NaH₂PO₄ powder, respectively.
- (3) Electrochemical-oxidation of NiS₂, NiSe₂, and Ni₅P₄ in 1 M KOH. The electro-oxidation process was conducted under 10 mA cm⁻² for 10h, with 1M KOH as the electrolyte, NiS₂ (NiSe₂, or Ni₅P₄) as the working electrode, Pt as the counter electrode, and Hg/HgO electrode as the reference electrode. The final product was denoted as X-NiOOH (X=NiS₂, NiSe₂, Ni₅P₄).
- (4) Collection of X-Ni(OH)₂ (X=NiS₂, NiSe₂, Ni₅P₄) powder. The X-NiOOH (X=NiS₂, NiSe₂, Ni₅P₄) samples were washed in DI water for several times to remove the residual impurity species. Then, the samples were immersed into the absolute ethanol solution for 1h to fully transfer the NiOOH to Ni(OH)₂. Next, the X-Ni(OH)₂ (X=NiS₂, NiSe₂, Ni₅P₄) powder in absolute ethanol solution was obtained through a sonication process. After standing still for 1h, the upper solution was separated and dried at 70 °C for 24h. After that, the X-Ni(OH)₂ (X=NiS₂, NiSe₂, Ni₅P₄) powder was collected.
- (5) **Preparation of NiFe LDH.** The NiFe LDH was grown on the carbon cloth via the same hydrothermal process as the synthesis of Ni(OH)₂.

Removal of Fe impurity. The 1M KOH solution was purified to remove Fe impurity before use. The procedure was as follows: First, $0.5 \text{ g Ni}(\text{NO})_3 \cdot 6\text{H}_2\text{O}$ powder was added into 30 mL 1M KOH solution, forming Ni(OH)₂ precipitation. Next, the suspension was centrifuged at 10000 r/min for 3 times. The centrifugation process was repeated for 3 times. Then, the obtained Ni(OH)₂ powder was added into 50 mL KOH solution and mechanically agitated for 10 min. After standing still for 24h, the suspension was centrifuged with the KOH supernatant decanted into a clean electrochemical cell for use.

Material Characterizations. The XRD patterns were measured by a Bruker D8 X-ray diffractometer where the Cu K α radiation ($\lambda = 1.5406$ Å) was equipped. The SEM images were obtained using ZEISS SEM Supra 40. The Raman spectra were recorded by a Raman Spectrophotometer with an excitation wavelength of 514.4 nm. The XPS was measured by a Kratos Analytical Axis Ultra DLD UHV spectrometer equipped with Al Ka X-ray irradiation source (1486.6 eV). Nickel K-edge X-ray absorption fine structure (XAFS) spectra were recorded at the XAFCA beamline at the Singapore Synchrotron Light Source(SSLS) under transmission mode where the storage ring is running at 0.7 GeV with current nearly 200mA.¹ The energy calibrations were finished by using standard Nickel foil. The k²-weighted Fourier transforms were conducted using the Hanning window function for the EXAFS results, with the k-range of 2.5-10.5Å⁻¹. The Nickel L_{2,3}-edge and Oxygen K-edge Near-edge X-ray absorption fine structure (NEXAFS) spectra were also recorded at the SUV beamline of SSLS. The data was collected under total electron yield mode with the photon energy resolution of 350 meV. The photon energy was calibrated through the characteristic intensity dip based on the contamination carbon of the beamline optical components at 284.4 eV. The NEXAFS data was normalized to the incident photon intensity (I₀) monitored by the focusing mirror. The particle size analysis was conducted via Zetasizer.

Electrochemical measurements.

All the electrochemical measurements were performed using an electrochemical workstation (VPM3, BiO-logic Inc) in a three-electrode setup in 1M KOH. The workstation is equipped with built-in electrochemical impedance spectroscopy (EIS) analyser. The working electrode was the X-NiOOH (X=NiS₂, NiSe₂, Ni₅P₄). The Hg/HgO was chosen as the reference electrode. The Pt was used as the counter electrode. The linear scan voltammetry (LSV) was measured at scan rate 0.1 mV s⁻¹. The Tafel plots were derived by plotting the overpotential η (mV) versus the log current density(log[*J*]). The Tafel slope was obtained via linearly fitting the linear portion of the Tafel plots according to the Tafel equation (η =b log[*J*] +a, b is the Tafel slope). The potential electrochemical impedance spectroscopy (EIS) measurements were conducted at open circuit potential with the frequency set from 10 mHz to 100 kHz.

Electrochemically surface area. The electrochemically surface area (ECSA) data was evaluated from recording the electrochemical double-layer capacitance of the catalyst via cyclic voltammograms (CVs). Here, the potential range was set at 0.02-0.12 V (versus Hg/HgO) to avoid the Faradaic process. The CVs were conducted in the quiescent electrolyte with the potential swept across the set potential range with at 6 scan rates 5, 10, 20, 30, 40, 50 mV s⁻¹. The charging current was plotted versus scan rate and a straight line could be derived with the slope value equalled to the double-layer capacitance (C_{dl}). The ECSA was obtained by dividing the C_{dl} to the specific capacitance $C_s = 0.04$ mF cm⁻².²

Pulse-voltammetry test.³ For preparing glassy carbon electrode, 4 mg of the collected X-Ni(OH)₂(X=NiS₂, NiSe₂, Ni₅P₄) powder was added into the 750 uL DI water, 250 uL isopropanol and 20 uL (5wt.%) Nafion solution followed by at least 60 min sonication to obtain a uniform ink. Then 10 uL of the ink was pipetted onto the glassy carbon (loading mass:0.516 mg cm⁻²) and air dried at room-temperature for 12 h before electrochemical tests. Before the pulse voltammetry (P-V) test, an electrochemical activation process under 10 mA cm⁻² for 1h in 1M KOH electrolyte was applied for the samples coated on the glassy carbon electrode. The potential was set firstly at a low potential (E₁) for 6s, then turned to a higher potential (E_h) for 6s before back to E₁ for 6s.

This cycle was repeated while increasing E_h from 1.42 V to 1.68 V versus RHE in 20 mV/step with constant $E_l = 1.4$ V. The transferred charge normalized to ECSA during each cycle was evaluated by integrating the current pulse/ECSA over time.

Computational method. All calculations were conducted via the DFT with the generalized Perdew-Burke-Ernzerhof (PBE), and the projector augmented-wave (PAW) pseudopotential planewave method as implemented in the Vienna *ab initio* Simulation Package (VASP) code. The X-Ni(OH)₂ (X=NiS₂, NiSe₂, Ni₅P₄) and benchmark Ni(OH)₂ construction are based on the fitted Ni-O bond distances results. (Table. S2)



Fig. S1.

Schematic illustration of the synthesis route for the $NiS_2/NiSe_2/Ni_5P_4$ -NiOOH. All the experimental procedures are kept the same except for the anion source.



Fig. S2.

(a) TEM image of NiS₂, the estimated area of the highlighted particle was ~ 2931 nm². (b) TEM image of NiSe₂, the estimated area of the highlighted particle was ~3011 nm². (c) TEM image of Ni₅P₄, the estimated area of the highlighted particle was ~2734 nm².



Fig. S3.

(a) HRTEM image of NiS₂. (b) magnified region as indicated by the rectangular area in (a). (c) TEM image and corresponding EDS elemental mapping of NiS₂. (d) HRTEM image of NiSe₂. (e) magnified region as indicated by the rectangular area in (d). (f) TEM image and corresponding EDS elemental mapping of NiSe₂. (g) HRTEM image of Ni₅P₄. (h) magnified region as indicated by the rectangular area in (g). (i) TEM image and corresponding EDS elemental mapping of NiSe₂.

















The electro-oxidation of prepared (a)NiS₂, (b) NiSe₂, (c) Ni₅P₄ using Chronopotentiometry. The electro-oxidation current density is set as 10 mA cm⁻².



Fig. S8. Ni *L*_{2,3}-edge spectra of X-Ni(OH)₂ (X=NiS₂,NiSe₂,Ni₅P₄) with Ni(OH)₂ as benchmark.

These X-Ni(OH)₂ all show quite similar profile in comparison with Ni(OH)₂, indicating roughly all of the Ni atoms are arranged in the NiO₆ octahedral site.



Fig. S9. SEM-EDS result of NiS2-Ni(OH)₂.No S signal was detected.

Fig. S10. SEM-EDS result of NiSe₂-Ni(OH)₂. No Se signal was detected.

Fig. S11. SEM-EDS result of Ni₅P₄-Ni(OH)₂. No P signal was detected.

Fig. S12.

TEM-EDS result of NiS₂-Ni(OH)₂. The atomic Ni, O, C, and S compositions were 70.61%, 24.35%, 4.92%, and 0.12%, respectively.

Fig. S13.

TEM-EDS result of NiSe₂-Ni(OH)₂. The atomic Ni, O, C, and Se compositions in the material were 40.35%, 36.62%, 23.03%, and 0.00%, respectively.

Fig. S14.

TEM-EDS result of Ni_5P_4 - $Ni(OH)_2$. The atomic Ni, O, C, and P compositions in the material were 78.91%, 9.84%, 10.94%, and 0.31%, respectively.

Fig. S15.

The Cyclic voltammograms curves and current vs. scan rate plots of the (a)-(b) NiS₂-NiOOH (c)-(d) NiSe₂-NiOOH, (e)-(f) Ni₅P₄-NiOOH, (g)-(h) NiOOH. Plots of current vs. scan rate data were obtained from CV curves at 0.98 V. The ECSA for all samples was calculated as: NiS₂-NiOOH (165.75 cm²), NiSe₂-NiOOH (143.00 cm²), Ni₅P₄-NiOOH (136.10 cm²), and NiOOH (114.88 cm²).

Fig. S16.

Potential electrochemical impedance spectroscopy data for X-NiOOH (X=NiS₂, NiSe₂, Ni₅P₄) and benchmark NiOOH obtained at open circuit potential. The Ru (solution resistance) is used for *iR*correction, which is 1.18 Ω , 1.18 Ω , 1.17 Ω , 1.40 Ω for NiS₂-NiOOH, NiSe₂-NiOOH, Ni₅P₄-NiOOH, and NiOOH, respectively.

Fig. S17.

(a) OER polarization curves of the X-NiOOH (X = NiS₂, NiSe₂, Ni₅P₄) after *iR*-correction. (b) OER polarization curves of the X-NiOOH (X = NiS₂, NiSe₂, Ni₅P₄) after *iR*-correction normalization to ECSA. (c) OER polarization curves of the X-NiOOH (X = NiS₂, NiSe₂, NiSe₂, Ni₅P₄) after *iR*-correction normalization to mass loading, which are 1.06 mg/cm², 1.10 mg/cm², 0.97 mg/cm², and 0.95 mg/cm² for NiS₂-NiOOH, NiSe₂-NiOOH, Ni₅P₄-NiOOH, and NiOOH.

Fig. S18.

The influence of dissolute anion species on the OER activity of NiOOH. The overpotentials are 343 mV, 355 mV, 337 mV, 353 mV for NiOOH in 1M KOH, 0.2 mM PO_4^{3-} + 1M KOH, 0.2 mM SO_3^{2-} + 1M KOH, 0.2 mM SO_4^{2-} + 1M KOH solution, respectively.

Fig. S19.

The orbital diagram of regular high spin Ni²⁺. The NiO₆ octahedron distortion would lead to the 4p orbital and e_g^* orbital splitting.

Fig. S20.

Particle size distribution analysis by Zetasizer for X-Ni(OH)₂ (X=S, Se, P) and hydrothermal prepared Ni(OH)₂.

Fig. S21.

a. Normalized O *K*-edge XAS spectra of X-Ni(OH)₂ (X=NiS₂, NiSe₂, Ni₅P₄) with hydrothermal prepared Ni(OH)₂ as benchmark. **b.** Enlarged O *K* pre-edge region from **a**.

Fig. S22.

a. Ni 2p XPS spectra of X-Ni(OH)₂ (X=NiS₂, NiSe₂, Ni₅P₄). **b.** O 1s XPS spectra of X-Ni(OH)₂ (X=NiS₂, NiSe₂, N

Fig. S23. Magnified absorption ~0.5 region of Ni *K*-edge spectra.

Fig. S24.

(a) The molecular orbital diagram of octahedral NiO₆. (b)Schematic energy band of NiO₆ in consideration of Mott-Hubbard splitting. For the bonding bands including a_{1g} , t_{1u} , e_g , and t_{2g} , they show oxygen character (denoted as M-O). For the antibonding bands (M-O)^{*}, *i.e.*, t_{2g}^* , a_{1g}^* , t_{1u}^* , and e_g^* , they show metal character. Here, t_{2g}^* contains d_{xy} , d_{yz} and d_{xz} orbitals and e_g^* includes d_z^2 and $d_{x^2-y^2}$ orbitals, respectively. Among these electronic bands, the (M-O) and t_{2g}^* are fully occupied, while e_g^* is partially occupied with one spin-up electron each in the d_z^2 orbital and $d_{x^2-y^2}$ orbital. Due to the on-site electron repulsion within the *d* orbitals, antibonding bands will split into an empty upper- and filled lower-Hubbard bands (denoted as UHB and LHB, respectively), with an energy difference U.

Fig. S25. The calculated e_g^* band density of states (DOS) of X-Ni(OH)₂ (X = NiS₂, NiSe₂ and Ni₅P₄).

Fig. S26.

Potential versus log(current) from pulse voltammetry. (normalization to ECSA) (a) NiS_2 -NiOOH. (b) $NiSe_2$ -NiOOH. (c) Ni_5P_4 -NiOOH. (d) NiOOH. The slope is used to represent the charge transfer ability.

Fig. S27.

The correlation between NiO₆ distortion and e_g^* band broadening. Here, the normalized white line intensity from Ni *K*-edge spectra (Fig. 3a) is used to identify the geometry distortion extent in Ni(OH)₂. On the other hand, the normalized peak intensity at 532.5 eV adopted from Fig.3d (corresponding to the e_g^* splitting) is used to represent the e_g^* band broadening extent around the Fermi level.

Fig. S28. Calculated *d*-band center for X-Ni(OH)₂ (X=NiS₂, NiSe₂, Ni₅P₄)

Fig. S29. The XRD results of $Ni_{0.95}Fe_{0.05}(OH)_2$ and $Ni_{0.8}Fe_{0.2}(OH)_2$.

Fig. S30.

Potential versus log(current) from pulse voltammetry. (normalized to ECSA) (a) $Ni_{0.95}Fe_{0.05}OOH$. (b) $Ni_{0.8}Fe_{0.2}OOH$.

Fig. S31.

The Cyclic voltammograms curves and current vs. scan rate plots of the (a)-(b) $Ni_{0.95}Fe_{0.05}OOH$, (c)-(d) $Ni_{0.8}Fe_{0.2}OOH$. Plots of current vs. scan rate data were obtained from CV curves at 0.98 V. The ECSA for all samples was calculated as: $Ni_{0.95}Fe_{0.05}OOH/CC$ (160.93 cm²), $Ni_{0.8}Fe_{0.2}OOH/CC$ (181.66 cm²).

Fig. S32.

(a) OER polarization curves of the Ni_xFe_{1-x}OOH (x=1, 0.95, 0.8) normalization to ECSA. (b) OER polarization curves of the Ni_xFe_{1-x}OOH (x=1, 0.95, 0.8) normalization to mass loading. The NiOOH is regards as the active species and its loading mass in Ni_{0.95}Fe_{0.05}OOH and Ni_{0.8}Fe_{0.2}OOH is evaluated as 0.55 mg cm⁻², and 0.51 mg cm⁻², respectively.

Fig. S33.

Potential electrochemical impedance spectroscopy data for Ni_{1-x}Fe_xOOH (x=0, 0.05, 0.2) at open circuit potential. Ru (solution resistance) was used for *IR*-correction, which was 1.03 Ω , 1.13 Ω , 1.40 Ω for Ni_{0.8}Fe_{0.2}OOH, Ni_{0.95}Fe_{0.05}OOH, and NiOOH, respectively.

Fig. S34.

(a) OER polarization curves of Ni_{1-x}Fe_xOOH (x=0, 0.05, 0.2) after *iR*-correction. (b) OER polarization curves of Ni_{1-x}Fe_xOOH (x=0, 0.05, 0.2) after *iR*-correction normalized to ECSA. (c) OER polarization curves of Ni_{1-x}Fe_xOOH (x=0, 0.05, 0.2) after *iR*-correction normalized to mass loading. NiOOH is regarded as the active species and its loading mass in Ni_{0.95}Fe_{0.05}OOH and Ni_{0.8}Fe_{0.2}OOH was evaluated as 0.55 mg cm⁻², and 0.51 mg cm⁻², respectively.

Table S1.

Samples	Ni (w/w%)	S(w/w%)	Se(w/w%)	P(w/w%)
NiS ₂	44.11	51.79	/	\
NiS ₂ -Ni(OH) ₂	45.35	N/A	\	\
NiSe ₂	23.46	\	66.51	\
NiSe ₂ -Ni(OH) ₂	43.57	\	0.13	\
Ni ₅ P ₄	65.85	\	\	28.26
Ni ₅ P ₄ -Ni(OH) ₂	41.27	\	\	0.08

ICP/CNHS results of NiS₂,NiSe₂, and Ni₅P₄ before and after chronopotentiometry treatment

Table S2.

Fitted mean Ni-O bond distances in X-Ni(OH)₂ (X=NiS₂, NiSe₂, Ni₅P₄) and benchmark Ni(OH)₂

Samples	R(Å)
NiS ₂ -Ni(OH) ₂	2.03916
NiSe ₂ -Ni(OH) ₂	2.04688
Ni ₅ P ₄ -Ni(OH) ₂	2.04875
Ni(OH) ₂	2.05876

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